

#17/C
Amend/c
Y. Polkinghorn
7/28/03

566.40894X00

EXPEDITED PROCEDURE PURSUANT
TO 37 CFR §1.116 REQUESTED

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: K. HORIKOSHI et al

Serial No.: 09/988,585

Filed: November 20, 2001

For: THIN-FILM TRANSISTOR AND METHOD OF
MANUFACTURING THE SAME

Group: 2811

Examiner: T. TRAN

AMENDMENT AFTER FINALMS: After Final

June 27, 2003

Commissioner For Patents
POB 1450
Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action, dated February 27, 2003, the period of response for which extension of time is requested in the attached Petition for Extension of Time, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:Please cancel claim 2 without prejudice or disclaimer and amend claims

1 and 9 to read as follows:

CJ bulk D1

1. (Twice Amended) A thin-film transistor comprising:
a glass substrate; and